TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT process)

# 2SA1204

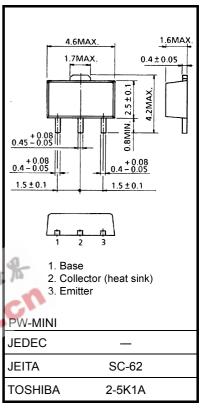
### **Audio Frequency Amplifier Applications**

Unit: mm

- High DC current gain: hFE = 100 to 320
- Suitable for output stage of 1 watts amplifier
- · Small flat package
- PC = 1.0 to 2.0 W (mounted on a ceramic substrate)
- Complementary to 2SC2884

### **Absolute Maximum Ratings (Ta = 25°C)**

| Characteristics             | Symbol           | Rating     | Unit |  |
|-----------------------------|------------------|------------|------|--|
| Collector-base voltage      | $V_{CBO}$        | -35        | V    |  |
| Collector-emitter voltage   | V <sub>CEO</sub> | -30        | V    |  |
| Emitter-base voltage        | V <sub>EBO</sub> | -5         | V    |  |
| Collector current           | Ic               | -800       | mA   |  |
| Base current                | ΙΒ               | -160       | mA   |  |
| Collector power dissipation | PC               | 500        | カー   |  |
|                             | PC               | 1000       | mW   |  |
|                             | (Note 1)         | 1000       | C    |  |
| Junction temperature        | Τj               | 150        | °C   |  |
| Storage temperature range   | T <sub>stg</sub> | −55 to 150 | °C   |  |



Weight: 0.05 g (typ.)

Note 1: Mounted on a ceramic substrate (250 mm<sup>2</sup> × 0.8 t)

Note 2: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

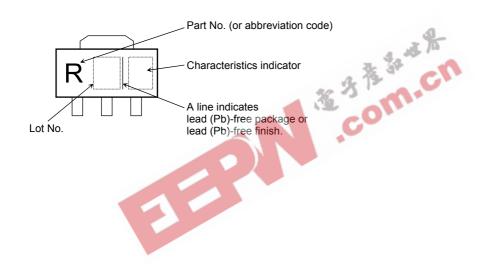
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

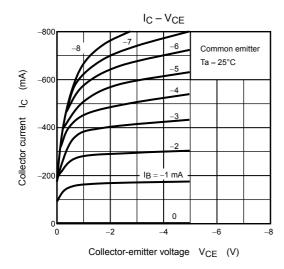
# **Electrical Characteristics (Ta = 25°C)**

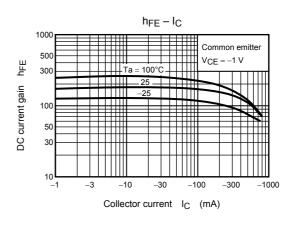
| Characteristics                      | Symbol                          | Test Condition   | Min  | Тур. | Max  | Unit |
|--------------------------------------|---------------------------------|--|------|------|------|------|
| Collector cut-off current            | I <sub>CBO</sub>                | $V_{CB} = -35 \text{ V}, I_E = 0$                      | _    | _    | -0.1 | μΑ   |
| Emitter cut-off current              | I <sub>EBO</sub>                | $V_{EB} = -5 \text{ V}, I_C = 0$                       | _    | _    | -0.1 | μA   |
| Collector-emitter breakdown voltage  | V (BR) CEO                      | $I_C = -10 \text{ mA}, I_B = 0$                        | -30  | _    | _    | V    |
| DC current gain                      | h <sub>FE (1)</sub><br>(Note 3) | V <sub>CE</sub> = -1 V, I <sub>C</sub> = -100 mA       | 100  | -    | 320  |      |
|                                      | h <sub>FE (2)</sub>             | V <sub>CE</sub> = -1 V, I <sub>C</sub> = -700 mA       | 35   | _    | _    |      |
| Collector-emitter saturation voltage | V <sub>CE</sub> (sat)           | I <sub>C</sub> = -500 mA, I <sub>B</sub> = -20 mA      | _    | _    | -0.7 | V    |
| Base-emitter voltage                 | $V_{BE}$                        | V <sub>CE</sub> = -1 V, I <sub>C</sub> = -10 mA        | -0.5 | _    | -0.8 | V    |
| Transition frequency                 | f <sub>T</sub>                  | V <sub>CE</sub> = -5 V, I <sub>C</sub> = -10 mA        | _    | 120  | _    | MHz  |
| Collector output capacitance         | C <sub>ob</sub>                 | V <sub>CB</sub> = -10 V, I <sub>E</sub> = 0, f = 1 MHz | _    | 19   | _    | pF   |

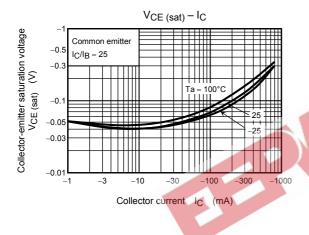
Note 3: h<sub>FE (1)</sub> classification O: 100 to 200, Y: 160 to 320

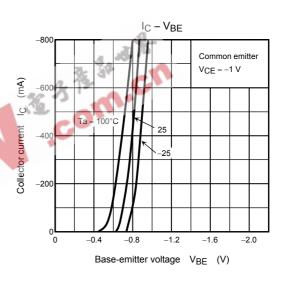
# Marking

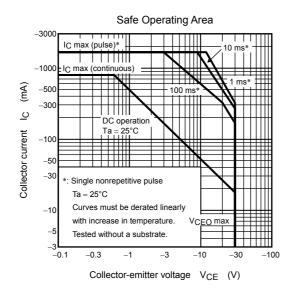


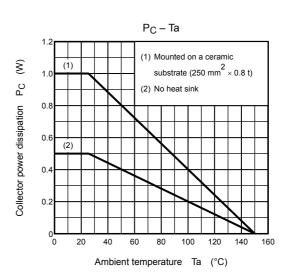












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